	ABLE STANDARD		-40°C to 85°C (Note 1)		Storage	_		-10°C TO 60	0°C	
RATING	Temperature Range				Temperature Range Applicable Connector					
	Voltage		30V AC/DC Signal contact : 0.	24	Applicable	Conne	CIOF	BM25-4S/2-V	**)	
	Current 🛆		Power contact : 10.							
					TIONS					
	ITEM					RI		REMENTS	QT	A
			TEGT METHOD				_0011		Q	Α
General Examination		Visually and by measuring instrument.			According to drawing.					Х
Marking		Confirmed visually.			According to drawing.				X X	X
ELECT		ACTERIS	TICS							
Contact Resistance		20mV AC or less 1kHz,1m A .			-			ce: 30 mΩ MAX.	Х	_
Insulation Resistance		100V DC.			Power contact resistance: 5 mΩ MAX.					
Voltage Proof					1000 MΩ MIN.				X	-
		150V AC for 1 min. No flashover or breakdown					UW11.	Х	-	
MECUA			DISTICS							
					(1) Sian	nal contac	t resis	tance: 30 mΩ MAX.		
Mechanical Operation		10 times insertions and extractions.			Pow	er contac	t resis	tance: 5 mΩ MAX.	х	_
						-		or looseness of parts.		
Vibration		Frequency 10 to 55 to 10 Hz, approx. 5min, Single amplitude 0.75 mm,10cycles,				(1) No electrical discontinuity of 1 μ s.				_
		for 3 directions.				② No damage, crack or Looseness of parts.				
Shock		490 m/s ² duration of pulse 11 ms at 3 times for 3 directions.			 No electrical discontinuity of 1 μs. No damage, crack or looseness of parts. 				Х	_
					I			•		
ENVIRC	ONMENTA		CTERISTICS							
			ire -55 → +85°C		- 0			tance: 30 m Ω MAX.		
Rapid Change of Temperature Damp Heat (Steady state)		Time Under 5 cv	Time $30 \rightarrow 30$ min Under 5 cycles.			Power contact resistance: 5 mΩ MAX. ② Insulation resistance: 1000MΩ MIN.				_
		(Relocation time to chamber : within 2-3 min)			③ No c	damage, d	crack o	or looseness of parts.	X	
					-			tance: 30 m Ω MAX.		
		Exposed at 40 ± 2 °C, 90 to 95 %, 96 h.			Power contact resistance: $5 \text{ m}\Omega \text{ MAX}$. (2) Insulation resistance: $100M\Omega \text{ MIN}$.				Х	_
					③ No damage, crack or looseness of parts.					
Sulphur Dioxide		Exposed in 25 PPM for 96h,25°C,75%. (Refer to JIS C 60068)			Signal contact resistance: $30 \text{ m}\Omega \text{ MAX}$. Power contact resistance: $5 \text{ m}\Omega \text{ MAX}$.					_
сои	NTC	ESCRIPTIO	N OF REVISIONS		DESIGNED			CHECKED	DA	ATE
COU	NT C		N OF REVISIONS		DESIGNED TR. YUNOK I			CHECKED TS. MIYAZAKI	DA 15.1	
1 REMARKS		DIS-H	-00001221			APPROV	/ED		15. 1 15. (12.2)3.2
1 REMARKS		DIS-H	-00001221			CHECK	ED	TS. MIYAZAKI Mo. Ishida yh. Michida	15.1 15.0 15.0	12.2)3.2)3.2
1 REMARKS Note1: Includ	de the temperatur	DIS-H e rising by curr	-00001221 ent	50512		CHECK	ED ED	TS. MIYAZAKI Mo. Ishida Yh. Michida TR. Yunoki	15.1 15.0 15.0 15.0	12.2)3.2)3.2)3.2
1 REMARKS Note1: Includ	de the temperatur	DIS-H e rising by curr ified, refer t	-00001221 ^{ent} o JIS C 5402 and IEC 6		TR. YUNOK I	CHECK DESIGN DRAW	ED ED	TS. MIYAZAKI MO. ISHIDA YH. MICHIDA TR. YUNOKI KR. AJITO	15. 1 15. 0 15. 0 15. 0 15. 0	12.2)3.2)3.2)3.2)3.2
1 REMARKS Note1: Includ Unless ot	de the temperatur herwise spec Qualification To	DIS-H e rising by curr ified, refer t est AT:Asse	-00001221 ent o JIS C 5402 and IEC 6 urance Test X:Applicable 1		TR. YUNOKI DRAWIN	CHECK DESIGN DRAW	ED ED N	TS. MIYAZAKI MO. ISHIDA YH. MICHIDA TR. YUNOKI KR. AJITO ELC-358234-5	15. 1 15. 0 15. 0 15. 0 15. 0	12.2)3.2)3.2)3.2)3.2
1 REMARKS Note1: Includ	de the temperatur herwise spec Qualification To	DIS-H e rising by curr ified, refer t est AT:Ass SPECIFIC	-00001221 ^{ent} o JIS C 5402 and IEC 6	Гest	TR. YUNOK I	CHECK DESIGN DRAW IG NO.	ED ED N	TS. MIYAZAKI MO. ISHIDA YH. MICHIDA TR. YUNOKI KR. AJITO	15. 1 15. 0 15. 0 15. 0 15. 0	12.2)3.2)3.2)3.2)3.2

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